ESP32-C3-WROOM-02 ESP32-C3-WROOM-02U

Datasheet

Module with flash and 15 GPIOs

Built around RISC-V single-core SoC

Supporting IEEE 802.11b/g/n (2.4 GHz Wi-Fi) and Bluetooth 5 (LE)



About This Document

This document provides specifications for the ESP32-C3-WROOM-02 and ESP32-C3-WROOM-02U modules.

Document Updates

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Revision History

For revision history of this document, please refer to the last page.

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1 Module Overview

1.1 Features

MCU

- ESP32-C3 embedded, 32-bit RISC-V single-core processor, up to 160 MHz
- 384 KB ROM
- 400 KB SRAM (16 KB for cache)
- 8 KB SRAM in RTC

Wi-Fi

- IEEE 802.11 b/g/n-compliant
- Center frequency range of operating channel: 2412 ~ 2484 MHz
- Supports 20 MHz, 40 MHz bandwidth in 2.4 GHz band
- 1T1R mode with data rate up to 150 Mbps
- Wi-Fi Multimedia (WMM)
- TX/RX A-MPDU, TX/RX A-MSDU
- Immediate Block ACK
- Fragmentation and defragmentation
- Transmit opportunity (TXOP)
- Automatic Beacon monitoring (hardware TSF)
- 4 × virtual Wi-Fi interfaces
- Simultaneous support for Infrastructure BSS in Station mode, SoftAP mode, Station + SoftAP mode, and promiscuous mode

Note that when ESP32-C3 family scans in Station mode, the SoftAP channel will change along with the Station channel

- · Antenna diversity
- 802.11mc FTM

Bluetooth®

- Bluetooth LE: Bluetooth 5, Bluetooth mesh
- Speed: 125 Kbps, 500 Kbps, 1 Mbps, 2 Mbps
- Advertising extensions
- Multiple advertisement sets
- Channel selection algorithm #2

Hardware

- Interfaces: GPIO, SPI, UART, I2C, I2S, remote control peripheral, LED PWM controller, general DMA controller, TWAI[®] controller (compatible with ISO 11898-1), USB Serial/JTAG controller, temperature sensor, SAR ADC
- 40 MHz crystal oscillator
- 4 MB SPI flash
- Operating voltage/Power supply: 3.0 ~ 3.6 V
- Operating ambient temperature:
 - 85 °C version module: -40 ~ 85 °C
 - 105 °C version module: -40 ~ 105 °C
- Dimensions: See Table 1

Test

HTOL/HTSL/uHAST/TCT/ESD/Latch-up

1.2 Description

ESP32-C3-WROOM-02 and ESP32-C3-WROOM-02U are two general-purpose Wi-Fi and Bluetooth LE module. The rich set of peripherals and high performance make the two modules an ideal choice for smart homes, industrial automation, health care, consumer electronics, etc.

ESP32-C3-WROOM-02 and ESP32-C3-WROOM-02U both feature a 4 MB external SPI flash. ESP32-C3-WROOM-

02 comes with a PCB antenna. ESP32-C3-WROOM-02U comes with a U.FL connector for an external IPEX antenna. ESP32-C3-WROOM-02 and ESP32-C3-WROOM-02U have two variants:

- 85 °C version operating at -40 ~ 85 °C
- 105 °C version operating at -40 ~ 105 °C

The two variants only differ in ambient operating temperature. In this datasheet unless otherwise stated, ESP32-C3-WROOM-02 refers to the ESP32-C3-WROOM-02 module in 85 °C and 105 °C versions, and ESP32-C3-WROOM-02U refers to the ESP32-C3-WROOM-02U module in 85 °C and 105 °C versions.

The ordering information for the two modules is as follows:

Table 1: Ordering Information

Module	Chip embedded Flash		Module dimensions (mm)		
ESP32-C3-WROOM-02	FSP32-C3	4 MB	18.0 × 20.0 × 3.2		
ESP32-C3-WROOM-02U	LOFUZ-UU	4 1010	18.0 × 14.3 × 3.2		

At the core of the two modules is ESP32-C3*, which has a 32-bit RISC-V single-core processor.

ESP32-C3 integrates a rich set of peripherals, ranging from UART, I2C, I2S, remote control peripheral, LED PWM controller, general DMA controller, TWAI® controller, USB Serial/JTAG controller, temperature sensor, and ADC. It also includes SPI, Dual SPI and Quad SPI interfaces.

Note:

1.3 Applications

- Smart Home
 - Light control
 - Smart button
 - Smart plug
 - Indoor positioning
- Industrial Automation
 - Industrial robot
 - Mesh network
 - Human machine interface (HMI)
 - Industrial field bus
- Health Care
 - Health monitor

- Baby monitor
- Consumer Electronics
 - Smart watch and bracelet
 - Over-the-top (OTT) devices
 - Wi-Fi and bluetooth speaker
 - Logger toys and proximity sensing toys
- Smart Agriculture
 - Smart greenhouse
 - Smart irrigation
 - Agriculture robot
- Retail and Catering
 - POS machines

^{*} For more information on ESP32-C3, please refer to ESP32-C3 Family Datasheet .

- Service robot
- Audio Device
 - Internet music players
 - Live streaming devices

- Internet radio players
- Generic Low-power IoT Sensor Hubs
- Generic Low-power IoT Data Loggers

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2 Block Diagram

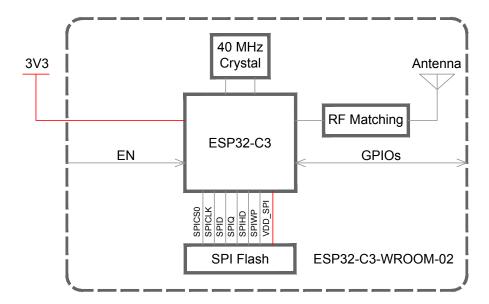


Figure 1: ESP32-C3-WROOM-02 Block Diagram

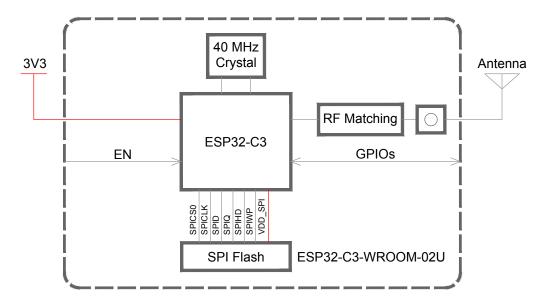


Figure 2: ESP32-C3-WROOM-02U Block Diagram

3 Pin Definitions

3.1 Pin Layout

The pin diagram below shows the approximate location of pins on the module. For the actual diagram drawn to scale, please refer to Figure 7.1 *Physical Dimensions*.

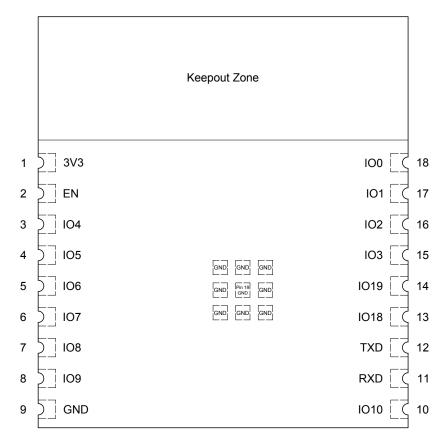


Figure 3: Pin Layout (Top View)

3.2 Pin Description

The module has 19 pins. See pin definitions in Table 2.

For peripheral pin configurations, please refer to *ESP32-C3 Family Datasheet*.

Table 2: Pin Definitions

Name	No.	Туре	Function
3V3	1	Р	Power supply
			High: on, enables the chip.
EN	2		Low: off, the chip powers off.
			Note: Do not leave the EN pin floating.
IO4	3	I/O/T	GPIO4, ADC1_CH4, FSPIHD, MTMS
IO5	4	I/O/T	GPIO5, ADC2_CH0, FSPIWP, MTDI
106	5	I/O/T	GPIO6, FSPICLK, MTCK

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Name No. **Function** Type 107 I/O/T GPIO7, FSPID, MTDO 6 **IO8** I/O/T GPI08 109 8 I/O/T GPIO9 **GND** 9,19 Ρ Ground IO10 10 I/O/T GPIO10, FSPICS0 RXD0 GPIO20, U0RXD I/O/T 11 TXD0 12 I/O/T GPIO21, U0TXD IO18 13 I/O/T GPIO18, USB_D-1019 14 I/O/T GPIO19, USB_D+ 103 15 I/O/T GPIO3, ADC1_CH3 102 16 I/O/T GPIO2, ADC1_CH2, FSPIQ 101 17 I/O/T GPIO1, ADC1_CH1, XTAL_32K_N 100 I/O/T GPIO0, ADC1_CH0, XTAL_32K_P 18

Table 2 - cont'd from previous page

3.3 Strapping Pins

Note:

The content below is excerpted from Section Strapping Pins in <u>ESP32-C3 Family Datasheet</u>. For the strapping pin mapping between the chip and modules, please refer to Chapter 5 *Module Schematics*.

ESP32-C3 family has four strapping pins:

- GPI02
- GPI08
- GPI09
- GPIO10

Software can read the values of GPIO2, GPIO8 and GPIO10 from GPIO_STRAPPING field in GPIO_STRAP_REG register. For register description, please refer to Section GPIO Matrix Register Summary in *ESP32-C3 Technical Reference Manual*.

During the chip's system reset, the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down.

Types of system reset include:

- power-on-reset
- RTC watchdog reset
- brownout reset
- analog super watchdog reset
- crystal clock glitch detection reset

By default, GPIO9 is connected to the internal pull-up resistor. If GPIO9 is not connected or connected to an external high-impedance circuit, the latched bit value will be "1"

To change the strapping bit values, you can apply the external pull-down/pull-up resistances, or use the host MCU's GPIOs to control the voltage level of these pins when powering on ESP32-C3 family.

After reset, the strapping pins work as normal-function pins.

Refer to Table 3 for a detailed boot-mode configuration of the strapping pins.

Table 3: Strapping Pins

	Booting Mode ¹					
Pin	Default	SPI Boot	Download Boot			
GPIO2	N/A	1	1			
GPIO8	N/A	Don't care	1			
GPIO9	Internal pull-up	1	0			
	Enab	oling/Disabling ROM Code Print Du	ring Booting			
Pin	Default	Functionality				
		When the value of eFuse field EFUS	E_UART_PRINT_CONTROL is			
		0 (default), print is enabled and not controlled by GPIO8.				
GPIO8	N/A	1, if GPIO8 is 0, print is enabled; if G	GPIO8 is 1, it is disabled.			
		2, if GPIO8 is 0, print is disabled; if 0	GPIO8 is 1, it is enabled.			
		3, print is disabled and not controlle	d by GPIO8.			
	Co	ontrolling JTAG Signal Source Durin	g Booting			
Pin	Default	Functionality				
		When the value of eFuse bit EFUSE	_STRAP_JTAG_SEL is			
GPIO10	N/A	0 (default), JTAG signals come from USB Serial/JTAG controller.				
GI IOTO		1, if GPIO10 is 0, JTAG signals come from chip pins;				
		if GPIO10 is 1, JTAG signals com	e from USB Serial/JTAG controller.			

¹ The strapping combination of GPIO8 = 0 and GPIO9 = 0 is invalid and will trigger unexpected behavior.

Figure 4 shows the setup and hold times for the strapping pin before and after the CHIP_EN signal goes high. Details about the parameters are listed in Table 4.

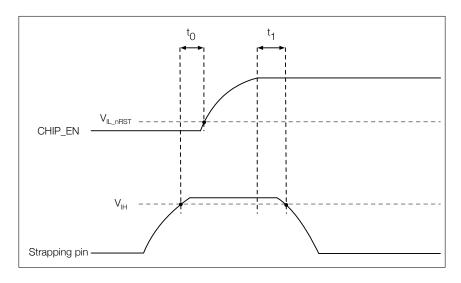


Figure 4: Setup and Hold Times for the Strapping Pin

Table 4: Parameter Descriptions of Setup and Hold Times for the Strapping Pin

Parameter	Description	Min (ms)
t_0	Setup time before CHIP_EN goes from low to high	0
t ₁	Hold time after CHIP_EN goes high	3

Electrical Characteristics

Absolute Maximum Ratings 4.1

Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 5: Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
VDD33	Power supply voltage	-0.3	3.6	V
T_{STORE}	Storage temperature	-40	150	°C

Recommended Operating Conditions

Table 6: Recommended Operating Conditions

Symbol	Parameter			Тур	Max	Unit
VDD33	Power supply voltage			3.3	3.6	V
$ V_{VDD} $	Current delivered by external power supply			_	_	Α
T_A	Ambient	85 °C version	-40		85	°C
	temperature	105 °C version	<u>–</u> 40		105	C
Humidity	Humidity cond	dition	_	_	85	%RH

DC Characteristics (3.3 V, 25 °C)

Table 7: DC Characteristics (3.3 V, 25 °C)

Symbol	Parameter	Min	Тур	Max	Unit
C_{IN}	Pin capacitance	_	2	_	рF
V_{IH}	High-level input voltage	$0.75 \times VDD^1$		VDD ¹ + 0.3	V
V_{IL}	Low-level input voltage	-0.3		$0.25 \times VDD^1$	V
$ I_{IH} $	High-level input current			50	nA
$ I_{IL} $	Low-level input current	_		50	nA
V_{OH}^2	High-level output voltage	$0.8 \times VDD^1$		_	V
V_{OL}^2	Low-level output voltage	_		$0.1 \times VDD^1$	V
Larr	High-level source current (VDD1= 3.3 V,		40		mA
$ _{OH}$	$V_{OH} >= 2.64 \text{ V, PAD_DRIVER} = 3)$	_	40		ША
Lor	Low-level sink current (VDD 1 = 3.3 V, V $_{OL}$ =		28		mA
OL	0.495 V, PAD_DRIVER = 3)		20		ША
R_{PU}	Pull-up resistor	_	45		kΩ
R_{PD}	Pull-down resistor		45		kΩ

Cont'd on next page

Table 7 - cont'd from previous page

Symbol	Parameter	Min	Тур	Max	Unit
V_{IH_nRST}	Chip reset release voltage	$0.75 \times VDD^1$	_	VDD ¹ + 0.3	V
V_{IL_nRST}	Chip reset voltage	-0.3	_	$0.25 \times VDD^1$	V

¹ VDD is the I/O voltage for a particular power domain of pins.

4.4 Current Consumption Characteristics

With the use of advanced power-management technologies, the module can switch between different power modes. For details on different power modes, please refer to Section Low Power Management in ESP32-C3 Family Datasheet.

Table 8: Current Consumption Depending on RF Modes

Work mode	Des	cription	Peak (mA)
	TX RX	802.11b, 1 Mbps, @20.5 dBm	345
		802.11g, 54 Mbps, @18 dBm	285
Active (RF working)		802.11n, HT20, MCS 7, @17.5 dBm	280
Active (hr working)		802.11n, HT40, MCS 7, @17 dBm	280
		802.11b/g/n, HT20	82
		802.11n, HT40	84

¹ The current consumption measurements are taken with a 3.3 V supply at 25 °C of ambient temperature at the RF port. All transmitters' measurements are based on a 100% duty cycle.

Table 9: Current Consumption Depending on Work Modes

Work mode	Description		Тур	Unit
Modem-sleep ^{1, 2}	The CPU is	160 MHz	20	mA
Modern-Sieep ¹ , -	powered on ³	80 MHz	15	mA
Light-sleep	_		130	μΑ
Deep-sleep	RTC timer + RTC memory		5	μΑ
Power off	CHIP_PU is set to low level, the chip is powered off		1	μΑ

¹ The current consumption figures in Modem-sleep mode are for cases where the CPU is powered on and the cache idle.

 $^{^{2}}$ V_{OH} and V_{OL} are measured using high-impedance load.

² The current consumption figures for in RX mode are for cases when the peripherals are disabled and the CPU idle.

² When Wi-Fi is enabled, the chip may switch between Active and Modem-sleep modes. Therefore, current consumption changes accordingly.

³ In practice, software can adjust CPU's frequency according to CPU load to reduce current consumption.

4.5 Wi-Fi Radio

4.5.1 Wi-Fi RF Standards

Table 10: Wi-Fi RF Standards

Name		Description	
Center frequency range of operating channel ¹		2412 ~ 2484 MHz	
Wi-Fi wireless standard		IEEE 802.11b/g/n	
		11b: 1, 2, 5.5 and 11 Mbps	
Data rate	20 MHz	11g: 6, 9, 12, 18, 24, 36, 48, 54 Mbps	
Data Tale		11n: MCS0-7, 72.2 Mbps (Max)	
	40 MHz	11n: MCS0-7, 150 Mbps (Max)	
Antenna type		PCB antenna, IPEX antenna	

¹ Device should operate in the center frequency range allocated by regional regulatory authorities. Target center frequency range is configurable by software.

4.5.2 Wi-Fi RF Transmitter (TX) Specifications

Target TX power is configurable based on device or certification requirements. The default characteristics are provided in Table 11.

Table 11: TX Power with Spectral Mask and EVM Meeting 802.11 Standards

Rate	Min	Тур	Max
nate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	20.5	_
802.11b, 11 Mbps	_	20.5	
802.11g, 6 Mbps	_	20.0	_
802.11g, 54 Mbps	_	18.0	_
802.11n, HT20, MCS 0	_	19.0	_
802.11n, HT20, MCS 7	_	17.5	_
802.11n, HT40, MCS 0	_	18.5	_
802.11n, HT40, MCS 7		17.0	_

Table 12: TX EVM Test

Data	Min	Тур	SL ¹
Rate	(dB)	(dB)	(dB)
802.11b, 1 Mbps, @20.5 dBm	_	-24.5	-10
802.11b, 11 Mbps, @20.5 dBm	_	-25.0	-10
802.11g, 6 Mbps, @20 dBm	_	-23.0	-5
802.11g, 54 Mbps, @18 dBm	_	-28.0	-25
802.11n, HT20, MCS 0, @19 dBm		-23.5	-5
802.11n, HT20, MCS 7, @17.5 dBm	_	-30.5	-27

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Table 12 - cont'd from previous page

Rate	Min (dB)	Typ (dB)	SL ¹ (dB)
802.11n, HT40, MCS 0, @18.5 dBm	_	-26.5	-5
802.11n, HT40, MCS 7, @17 dBm	_	-30.5	-27

¹ SL stands for standard limit value.

4.5.3 Wi-Fi RF Receiver (RX) Specifications

Table 13: RX Sensitivity

Rate	Min	Тур	Max
nate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps		-98.0	_
802.11b, 2 Mbps		-96.0	_
802.11b, 5.5 Mbps		-93.0	_
802.11b, 11 Mbps	_	-88.6	_
802.11g, 6 Mbps		-93.0	_
802.11g, 9 Mbps		-92.0	_
802.11g, 12 Mbps		-90.8	_
802.11g, 18 Mbps	_	-88.4	_
802.11g, 24 Mbps		-85.4	_
802.11g, 36 Mbps	_	-82.0	_
802.11g, 48 Mbps	_	-78.0	
802.11g, 54 Mbps	_	-76.4	_
802.11n, HT20, MCS 0		-93.0	_
802.11n, HT20, MCS 1	_	-90.8	_
802.11n, HT20, MCS 2	_	-88.2	_
802.11n, HT20, MCS 3	_	-84.6	_
802.11n, HT20, MCS 4	_	-81.4	_
802.11n, HT20, MCS 5	_	-77.4	_
802.11n, HT20, MCS 6		-75.4	_
802.11n, HT20, MCS 7	_	-74.4	
802.11n, HT40, MCS 0	_	-90.0	_
802.11n, HT40, MCS 1		-87.6	_
802.11n, HT40, MCS 2	_	-84.8	_
802.11n, HT40, MCS 3	_	-81.8	_
802.11n, HT40, MCS 4	_	-78.4	_
802.11n, HT40, MCS 5	_	-74.4	_
802.11n, HT40, MCS 6	_	-72.6	_
802.11n, HT40, MCS 7	_	-71.2	

Table 14: Maximum RX Level

Rate	Min	Тур	Max
Tido	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps		5	_
802.11b, 11 Mbps	_	5	
802.11g, 6 Mbps		5	_
802.11g, 54 Mbps	_	0	
802.11n, HT20, MCS 0	_	5	_
802.11n, HT20, MCS 7		0	_
802.11n, HT40, MCS 0		5	_
802.11n, HT40, MCS 7		0	

Table 15: RX Adjacent Channel Rejection

Rate	Min	Тур	Max
nate	(dB)	(dB)	(dB)
802.11b, 1 Mbps		35	_
802.11b, 11 Mbps	_	35	_
802.11g, 6 Mbps	_	31	_
802.11g, 54 Mbps	_	14	_
802.11n, HT20, MCS 0		31	_
802.11n, HT20, MCS 7	_	13	_
802.11n, HT40, MCS 0	_	19	_
802.11n, HT40, MCS 7	_	8	_

Bluetooth LE Radio 4.6

4.6.1 Bluetooth LE RF Transmitter (TX) Specifications

Table 16: Transmitter General Characteristics

Parameter	Min	Тур	Max	Unit
RF transmit power	_	0	_	dBm
Gain control step	_	3	_	dB
RF power control range	-27		18	dBm

Table 17: Transmitter Characteristics - Bluetooth LE 1M

Parameter	Description	Min	Тур	Max	Unit
In-band emissions	$F = F0 \pm 2 MHz$	_	-37.62	_	dBm
	$F = F0 \pm 3 \text{ MHz}$	_	-41.95	_	dBm
	$F = F0 \pm > 3 \text{ MHz}$	_	-44.48	_	dBm
Modulation characteristics	$\Delta f1_{ ext{avg}}$	_	245.00	_	kHz
	$\Delta f2_{ ext{max}}$	_	208.00	_	kHz
	$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	_	0.93	_	_
Carrier frequency offset	_	_	-9.00	_	kHz
	$ f_0 - f_n _{n=2, 3, 4,k}$	_	1.17	_	kHz
Carrier frequency drift	$ f_1 - f_0 $	_	0.30	_	kHz
	$ f_{n}-f_{n-5} _{n=6, 7, 8,k}$		4.90	_	kHz

Table 18: Transmitter Characteristics - Bluetooth LE 2M

Parameter	Description	Min	Тур	Max	Unit
	F = F0 ± 4 MHz	_	-43.55	_	dBm
In-band emissions	F = F0 ± 5 MHz	_	-45.26	_	dBm
	$F = F0 \pm > 5 MHz$	_	-47.00	_	dBm
	$\Delta f 1_{ ext{avg}}$	_	497.00	_	kHz
Modulation characteristics	$\Delta f2_{\sf max}$	_	398.00	_	kHz
	$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	_	0.95	_	_
Carrier frequency offset	_	_	-9.00	_	kHz
	$ f_0 - f_n _{n=2, 3, 4,k}$	_	0.46	_	kHz
Carrier frequency drift	$ f_1 - f_0 $	_	0.70	_	kHz
	$ f_{n}-f_{n-5} _{n=6, 7, 8,k}$	_	6.80	_	kHz

Table 19: Transmitter Characteristics - Bluetooth LE 125K

Parameter	Description	Min	Тур	Max	Unit
	F = F0 ± 2 MHz	_	-37.90	_	dBm
In-band emissions	$F = F0 \pm 3 \text{ MHz}$	_	-41.00	_	dBm
	$F = F0 \pm > 3 MHz$		-42.50	_	dBm
Modulation characteristics	$\Delta f 1_{avg}$	_	252.00	_	kHz
Modulation Characteristics	$\Delta f1_{\sf max}$		200.00	_	kHz
Carrier frequency offset	_	_	-13.70	_	kHz
	$ f_0 - f_n _{n=1, 2, 3,k}$	_	1.52	_	kHz
Carrier frequency drift	$ f_0 - f_3 $	_	0.65	_	kHz
	$ f_{n}-f_{n-3} _{n=7, 8, 9,k}$		0.70	_	kHz

Table 20: Transmitter Characteristics - Bluetooth LE 500K

Parameter	Description	Min	Тур	Max	Unit
	$F = F0 \pm 2 MHz$	_	-37.90	_	dBm
In-band emissions	$F = F0 \pm 3 \text{ MHz}$	_	-41.30	_	dBm
	$F = F0 \pm > 3 \text{ MHz}$	_	-42.80	_	dBm
Modulation characteristics	$\Delta f2_{ ext{avg}}$	_	220.00	_	kHz
Modulation Characteristics	$\Delta f2_{ ext{max}}$	_	205.00	_	kHz
Carrier frequency offset	_	_	-11.90	_	kHz
	$ f_0 - f_n _{n=1, 2, 3,k}$	_	1.37	_	kHz
Carrier frequency drift	$ f_0 - f_3 $	_	1.09	_	kHz
	$ f_{n}-f_{n-3} _{n=7, 8, 9,k}$	_	0.51	_	kHz

4.6.2 Bluetooth LE RF Receiver (RX) Specifications

Table 21: Receiver Characteristics - Bluetooth LE 1M

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_		-97	_	dBm
Maximum received signal @30.8% PER	_	_	10		dBm
Co-channel C/I	_	_	7	_	dB
	F = F0 + 1 MHz	_	-4	_	dB
	F = F0 – 1 MHz	_	-4	_	dB
Adjacent channel selectivity C/I	F = F0 + 2 MHz	_	-29		dB
Adjacent channel selectivity C/I	F = F0 – 2 MHz	_	-31	_	dB
	$F \ge F0 + 3 MHz$	_	-33		dB
	$F \le F0 - 3 \text{ MHz}$	_	-35	_	dB
	$F \ge F0 + 4 MHz$	_	-35		dB
	$F \le F0 - 4 MHz$	_	-37		dB
Image frequency	_		-35	_	dB
Adjacent channel to image frequency	$F = F_{image} + 1 \text{ MHz}$	_	-40	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-33	_	dB
	30 MHz ~ 2000 MHz		-6	_	dBm
Out-of-band blocking performance	2003 MHz ~ 2399 MHz		-26	_	dBm
	2484 MHz ~ 2997 MHz	_	-25	_	dBm
	3000 MHz ~ 12.75 GHz	_	-5	_	dBm
Intermodulation	_	_	-30	_	dBm

Table 22: Receiver Characteristics - Bluetooth LE 2M

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-93	_	dBm
Maximum received signal @30.8% PER	_	_	5	_	dBm
Co-channel C/I	_	_	10	_	dB
	F = F0 + 2 MHz	_	-8	_	dB
	F = F0 – 2 MHz	_	-7	_	dB
Adjacent channel selectivity C/I	F = F0 + 4 MHz		-32		dB
Image frequency	F = F0 – 4 MHz	_	-34	_	dB
	$F \ge F0 + 6 MHz$	_	-39	_	dB
	$F \le F0 - 6 MHz$	_	-39	_	dB
	_	_	-32	_	dB
A diagont observed to improve functional	$F = F_{image} + 2 \text{ MHz}$	_	-39	_	dB
Adjacent channel to image frequency	$F = F_{image} - 2 \text{ MHz}^{(2)}$	_	-8	_	dB
	30 MHz ~ 2000 MHz	_	-12	_	dBm
Out of band blocking parformance	2003 MHz ~ 2399 MHz	_	-30	_	dBm
Out-of-band blocking performance	2484 MHz ~ 2997 MHz	_	-28	_	dBm
	3000 MHz ~ 12.75 GHz	_	-6	_	dBm
Intermodulation	_	_	-29	_	dBm

Table 23: Receiver Characteristics - Bluetooth LE 125K

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-105	_	dBm
Maximum received signal @30.8% PER	_	_	10	_	dBm
Co-channel C/I	_	_	2	_	dB
	F = F0 + 1 MHz	_	-6	_	dB
	F = F0 – 1 MHz	_	-4	_	dB
Adjacent channel calcutivity C/I	F = F0 + 2 MHz	_	-33	_	dB
Adjacent channel selectivity C/I	F = F0 - 2 MHz	_	-41	_	dB
	F ≥ F0 + 3 MHz	_	-37	_	dB
	F ≤ F0 − 3 MHz	_	-46	_	dB
	F ≥ F0 + 4 MHz	_	-40	_	dB
	F ≤ F0 − 4 MHz	_	-49	_	dB
Image frequency	_	_	-40	_	dB
Adjacent channel to image frequency	$F = F_{image} + 1 \text{ MHz}$	_	-46	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-37		dB

Table 24: Receiver Characteristics - Bluetooth LE 500K

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-101	_	dBm
Maximum received signal @30.8% PER	_	_	10	_	dBm
Co-channel C/I	_		3	_	dB

Cont'd on next page

Table 24 - cont'd from previous page

Parameter	Description	Min	Тур	Max	Unit
	F = F0 + 1 MHz	_	-6	_	dB
	F = F0 – 1 MHz	_	-7	_	dB
Adjacent channel selectivity C/I	F = F0 + 2 MHz	_	-34	_	dB
Adjacent channel selectivity C/1	F = F0 - 2 MHz	_	-37	_	dB
	$F \ge F0 + 3 MHz$	_	-38	_	dB
	$F \le F0 - 3 \text{ MHz}$	_	-40	_	dB
	$F \ge F0 + 4 MHz$	_	-40		dB
	$F \le F0 - 4 MHz$	_	-42	_	dB
Image frequency	_	_	-40		dB
Adjacent channel to image frequency	$F = F_{image} + 1 \text{ MHz}$	_	-45	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-38	_	dB

S

5 Module Schematics

This is the reference design of the module.

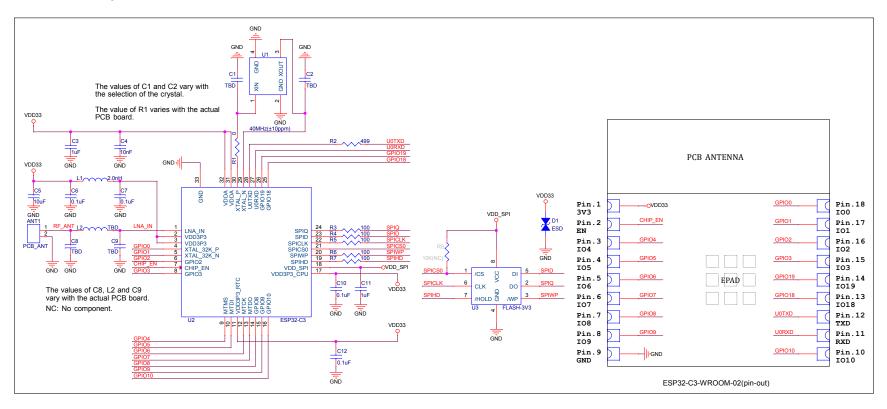


Figure 5: ESP32-C3-WROOM-02 Schematics

S

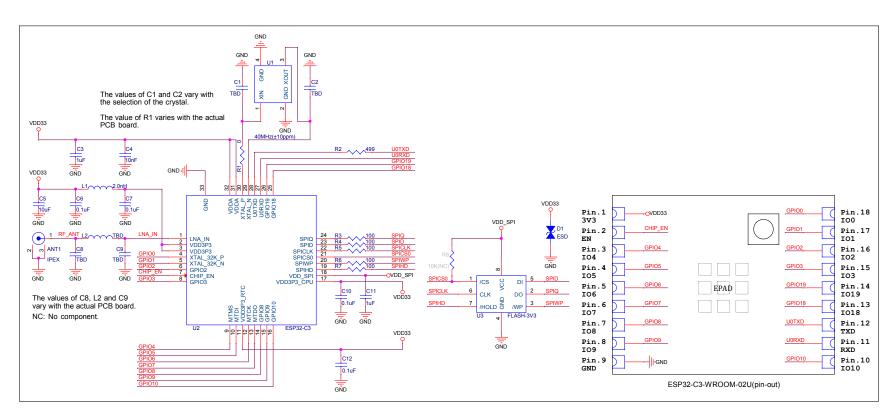


Figure 6: ESP32-C3-WROOM-02U Schematics

6 Peripheral Schematics

This is the typical application circuit of the module connected with peripheral components (for example, power supply, antenna, reset button, JTAG interface, and UART interface).

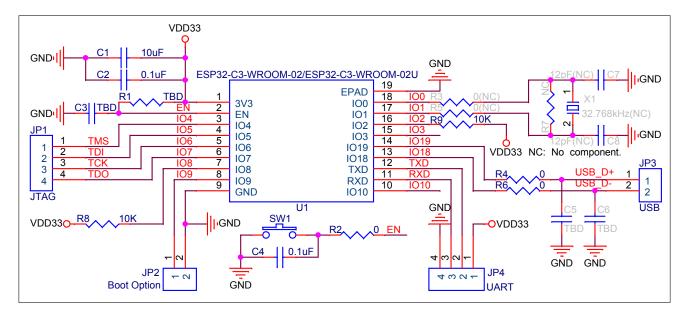


Figure 7: Peripheral Schematics

- Soldering the EPAD to the ground of the base board is not a must, though doing so can get optimized thermal performance. If you do want to solder it, please ensure that you apply the correct amount of soldering paste.
- To ensure the power supply to the ESP32-C3 family chip is stable during power-up, it is advised to add an RC delay circuit at the EN pin. The recommended setting for the RC delay circuit is usually R = 10 k Ω and C = 1 μ F. However, specific parameters should be adjusted based on the power-up timing of the module and the power-up and reset sequence timing of the chip. For power-up and reset sequence timing diagram of the ESP32-C3 family chip, please refer to Section *Power Scheme* in *ESP32-C3 Family Datasheet*.

7 Physical Dimensions and PCB Land Pattern

7.1 Physical Dimensions

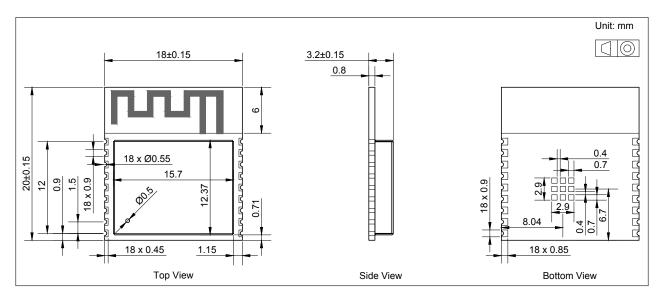


Figure 8: ESP32-C3-WROOM-02 Physical Dimensions

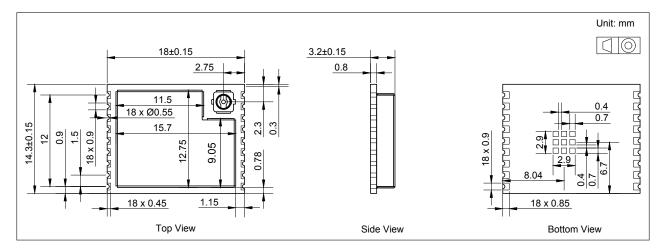


Figure 9: ESP32-C3-WROOM-02U Physical Dimensions

Recommended PCB Land Pattern

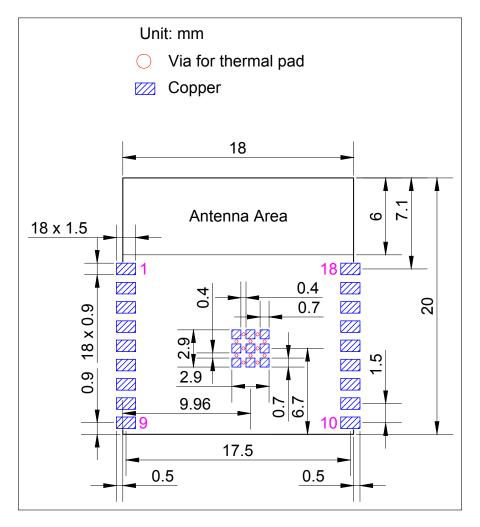


Figure 10: ESP32-C3-WROOM-02 Recommended PCB Land Pattern

Figure 11: ESP32-C3-WROOM-02U Recommended PCB Land Pattern

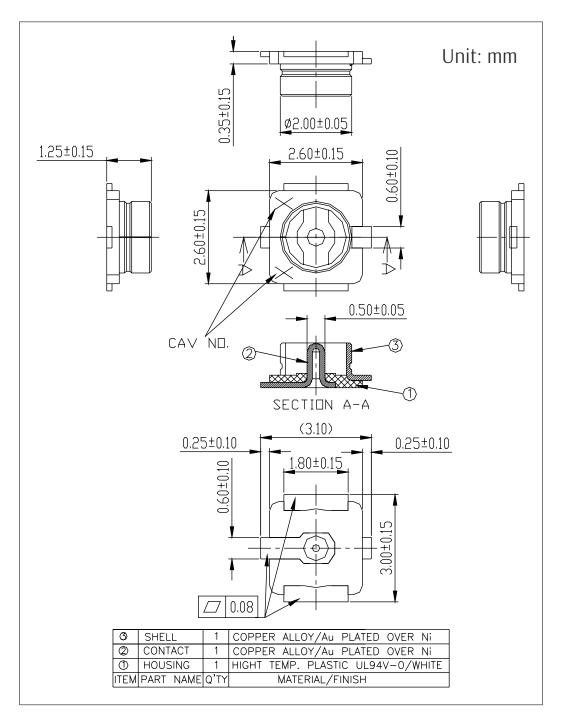


Figure 12: U.FL Connector Dimensions

8 Product Handling

8.1 Storage Conditions

The products sealed in moisture barrier bags (MBB) should be stored in a non-condensing atmospheric environment of < 40 °C and /90%RH. The module is rated at the moisture sensitivity level (MSL) of 3.

After unpacking, the module must be soldered within 168 hours with the factory conditions 25±5 °C and /60%RH. If the above conditions are not met, the module needs to be baked.

8.2 Electrostatic Discharge (ESD)

Human body model (HBM): 2000 VCharged-device model (CDM): 500 V

8.3 Reflow Profile

Solder the module in a single reflow.

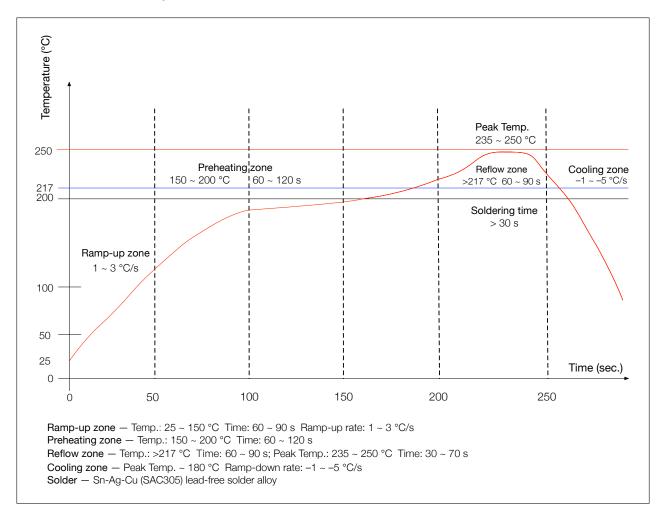


Figure 13: Reflow Profile

9 Learning Resources

9.1 Must-Read Documents

Please familiarize yourself with the following documents:

• ESP32-C3 Family Datasheet

This is an introduction to the specifications of ESP32-C3 family's hardware, including overview, pin definitions, functional description, peripheral interface, electrical characteristics, etc.

• ESP-IDF Programming Guide

Extensive documentation for the ESP-IDF development framework, ranging from hardware guides to API reference.

• ESP32-C3 Technical Reference Manual

Detailed information on how to use ESP32-C3 family's memory and peripherals.

• ESP32-C3 Hardware Design Guidelines

The guidelines outline recommended design practices when developing standalone or add-on systems based on the ESP32-C3 series of products, including ESP32-C3 SoCs, ESP32-C3 modules and ESP32-C3 development boards.

• Espressif Products Ordering Information

9.2 Important Resources

Here are the important ESP32-C3-related resources.

• ESP32 BBS

Engineer-to-Engineer (E2E) Community for Espressif products where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.

Revision History

Date	Version	Release notes
2021-04-16 V0.6		Added information about ESP32-C3-WROOM-02U module
2021-03-05 V0.5		Preliminary release



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